

L Number	Hits	Search Text	DB	Time stamp
39	62	laser near3 diode and bleach\$3 near3 absorb\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 16:44
40	45	laser near3 diode and bleach\$3 near3 absorb\$4 and shap\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:28
41	5	laser near3 diode\$1 and ((bleach\$3 or decolor\$3) near3 absorb\$4) and ingaas and vertical	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:13
44	0	laser near3 diode\$1 and bleach\$3 near3 absorb\$4 and current near3 constrict\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:29
45	0	laser near3 diode\$1 and bleach\$3 near3 absorb\$4 and current near3 block\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:29
46	0	laser near3 diode\$1 and bleach\$3 near3 absorb\$4 and current near3 oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:30
47	5	laser near3 diode\$1 and bleach\$3 near3 absorb\$4 and (vertical near3 (cavity or resonator))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:35
48	1262	laser near3 diode\$1 and bleach\$3 near3layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:35
49	64	laser near3 diode\$1 and bleach\$3 near3 layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:38
50	2	(laser near3 diode\$1 and bleach\$3 near3 layer) and 372/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:37
51	138	((laser near3 diode\$1) or (semiconductor near3 laser)) and bleach\$3 near3 absor\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:39
52	44	((laser near3 diode\$1) or (semiconductor near3 laser)) and bleach\$3 near3 absor\$6) and 372/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:55
53	29	((laser near3 diode\$1) same (saturable near3 absorb\$4)) and (bleach\$3 or transparent) and ingaas	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 17:59
54	9	((laser near3 diode\$1) same (saturable near3 absorb\$4)) and bleach\$3 and ingaas	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:05
55	10	(bragg or dbr) and ((saturable near3 absorb\$4) same bleach\$3) and ingaas	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:08
56	23	(bragg or dbr) and ((saturable near3 absorb\$4) same bleach\$3) and laser near3 diode\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:10

57	0	(bragg or dbr) and ((saturable near3 absorb\$4) same bleach\$3) and surfgace near3 emit\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:10
58	3	(bragg or dbr) and ((saturable near3 absorb\$4) same bleach\$3) and surface near3 emit\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:11
59	1	((saturable near3 absorb\$4) same bleach\$3) and 372/50.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:11
60	3	((saturable near3 absorb\$4) and bleach\$3) and 372/50.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:29
61	8	((saturable near3 absorb\$4) and bleach\$3) and (vertical near3 (cavity or resonator))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:13
66	0	((saturable near3 absorb\$4) and bleach\$3) and 372/96.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:29
67	41	(saturable near3 absorb\$4) and 372/96.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:31
68	0	(saturable near3 absorb\$4 near3 ingaas) and 372/96.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:30
69	3	((saturable near3 absorb\$4) same (bleach\$3 or transparent)) and 372/96.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:32
70	0	((saturable near3 absorb\$4) near3 (bleach\$3 or transparent)) and 372/96.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/05/31 18:33